TO-220 ĮĮĖ N ŏ MOS ĵ ů Ę ˥ N-CHANNEL MOSFET in a TO-220 Plastic Package.

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Low gate charge, low crss, fast switching.

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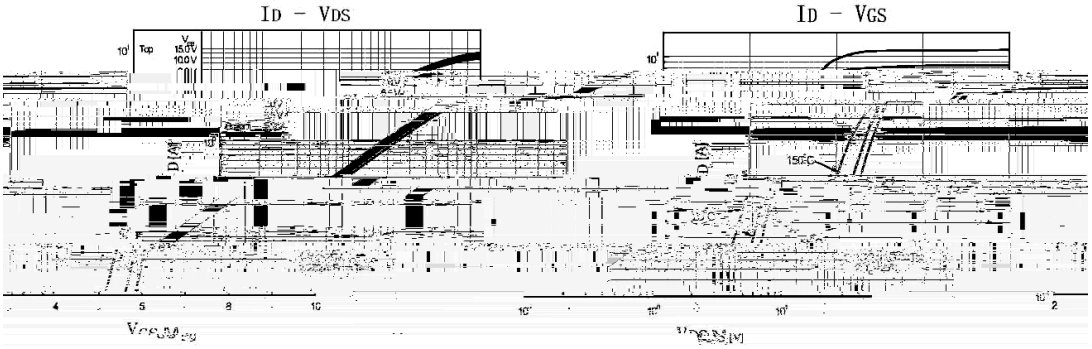
## / Absolute Maximum Ratings(Ta=25 )

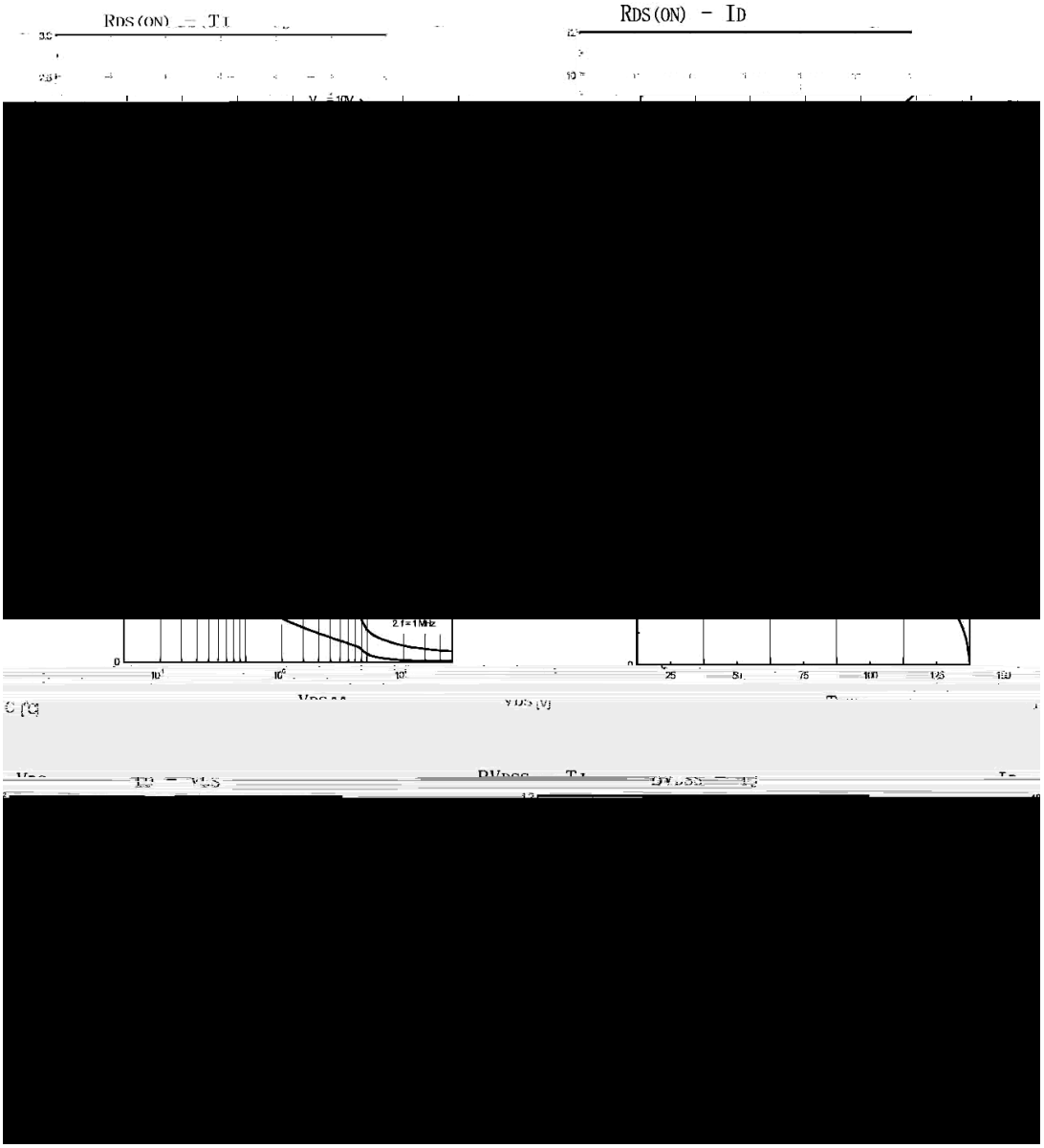
| v ̈Ω<br>Parameter | ϒ N<br>Symbol | ̈Ω Ö<br>Rating | D Ч<br>Unit |
|---|---|---|---|
| Drain-Source Voltage | $V_{DSS}$ | 600 | V |
| Drain Current | $I_D$(Tc=25 ) | 4.0 | A |
| | $I_D$(Tc=100 ) | 2.5 | A |
| Drain Current - Pulsed | $I_{DM}$ | 16 | A |
| Gate-Source Voltage | $V_{GSS}$ | ±30 | V |
| Single Pulsed Avalanche Energy | $E_{AS}$ | 240 | mJ |
| Repetitive Avalanche Energy | $E_{AR}$ | 10 | mJ |
| Avalanche Current | $I_{AR}$ | 4.0 | A |
| Power Dissipation | $P_D$(Tc=25 ) | 100 | W |
| Operating and Storage Temperature Range | $T_J$,$T_{STG}$ | -55 to 150 | |

## / Electrical Characteristics(Ta=25 )

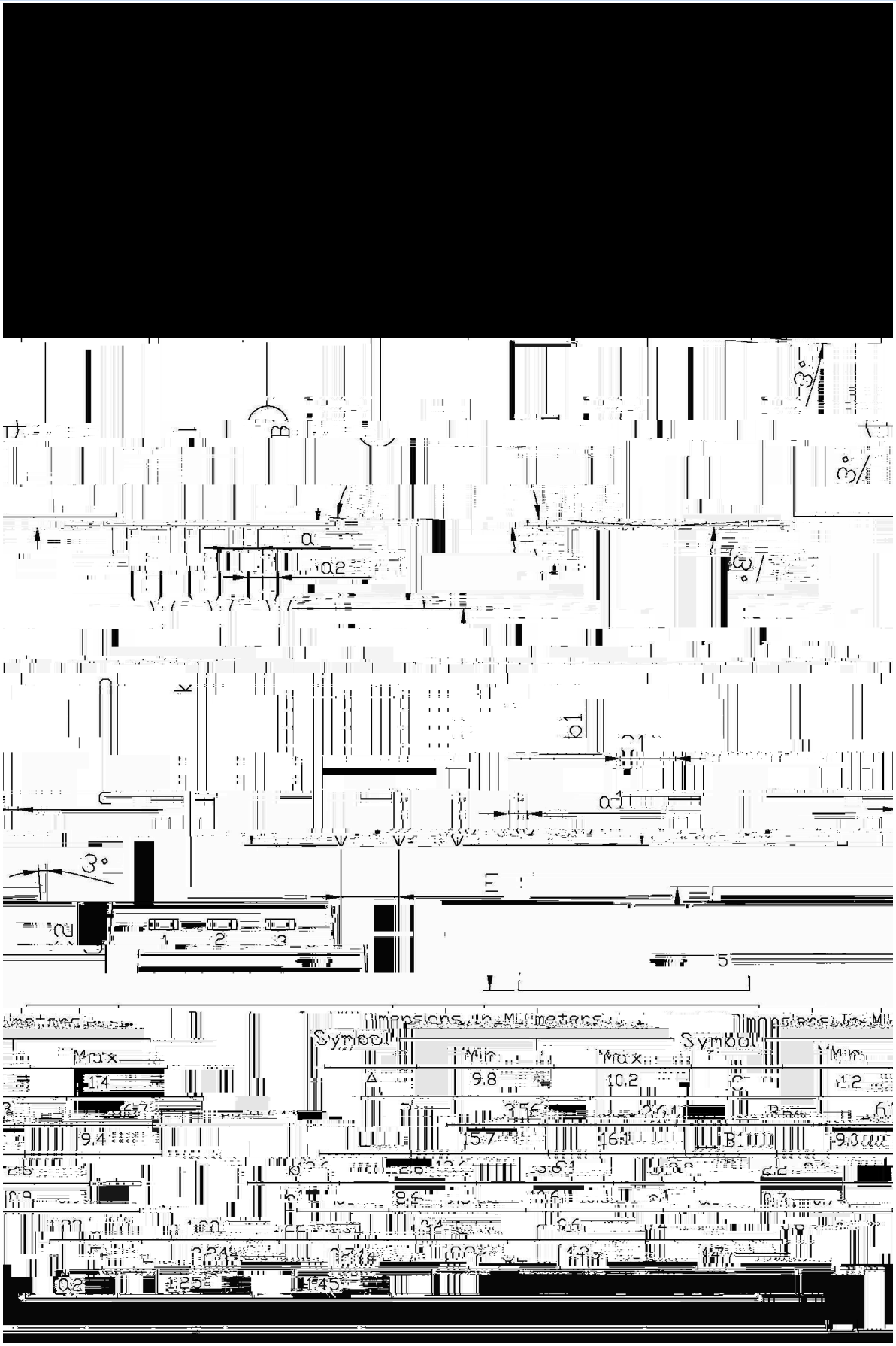
| v ̈Ω<br>Parameter | ϒ N<br>Symbol | Ш :ϒ Ţ<br>Test Conditions | ω ṇ Ö<br>Min | Ɛ ʒ Ö<br>Typ | ω ᶻ Ö<br>Max | D Ч<br>Unit |
|---|---|---|---|---|---|---|
| Drain-Source Breakdown Voltage | $BV_{DSS}$ | $V_{GS}$=0V $I_D$=250μA | 600 | | | V |
| Zero Gate Voltage Drain Current | $I_{DSS}$ | $V_{DS}$=600V $V_{GS}$=0V | | | 10 | μA |
| | | $V_{DS}$=480V $T_C$=125 | | | 100 | μA |
| Gate-Body Leakage Current, Forward | $I_{GSS}$ | $V_{GS}$=±30V $V_{DS}$=0V | | | ±0.1 | μA |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}$=$V_{GS}$ $I_D$=250μA | 2.0 | | 4.0 | V |
| Static Drain-Source On-Resistance | $R_{DS(on)}$ | $V_{GS}$=10V $I_D$=2.0A | | 2.0 | 2.5 | Ω |
| Forward Transconductance | $g_{FS}$ | $V_{DS}$=40V $I_D$=2.0A | | 4.7 | | S |
| Drain-Source Diode Forward Voltage | $V_{SD}$ | $V_{GS}$=0V $I_S$=4.0A | | | 1.4 | V |
| Input Capacitance | $C_{iss}$ | $V_{DS}$=25V $V_{GS}$=0V f=1.0MHz | | 545 | 710 | pF |
| Output Capacitance | $C_{oss}$ | | | 60 | 80 | pF |
| Reverse Transfer Capacitance | $C_{rss}$ | | | 8 | 11 | pF |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD}$=300V $I_D$=4.0A $R_G$=25Ω | | 10 | 30 | ns |
| Turn-On Rise Time | $t_r$ | | | 35 | 80 | ns |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 45 | 100 | ns |
| Turn-Off Fall Time | $t_f$ | | | 40 | 90 | ns |

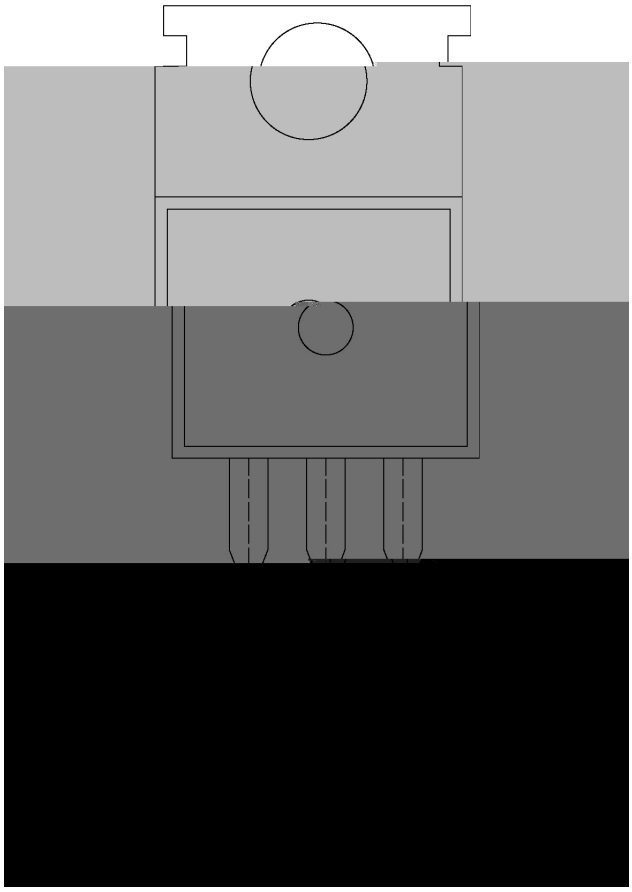
## / Electrical Characteristic Curve



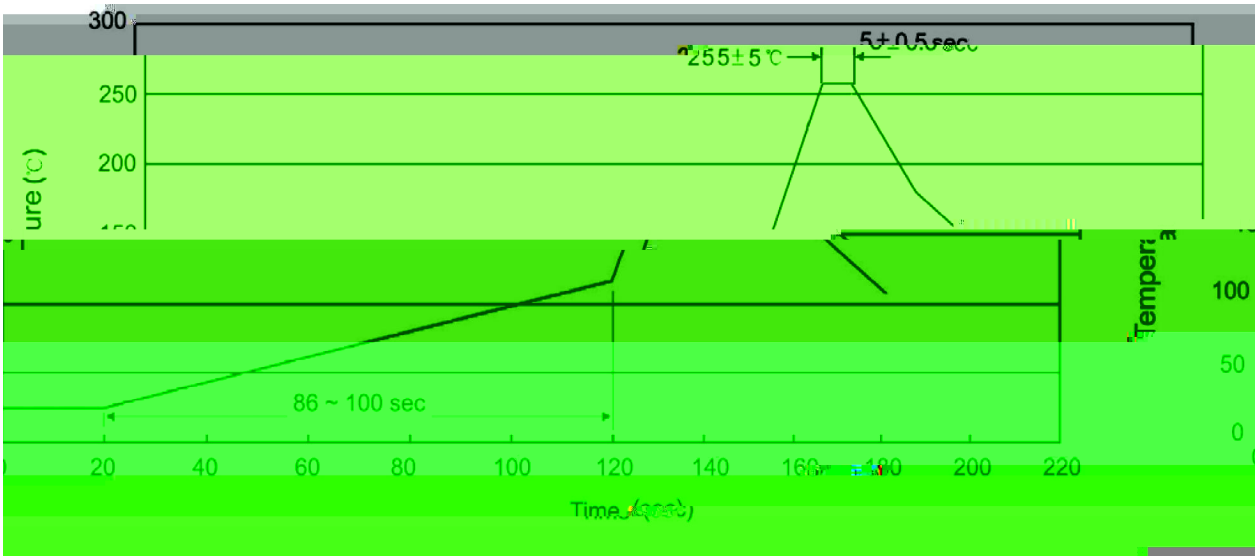



## / Package Dimensions





## ( ) / Temperature Profile for Dip Soldering(Pb-Free)




Note: